



ETL Systems

New technologies
in RF distribution

Model Number:
ALT-G1S-C5-114-xxxx

Alto C-Band Smart Amplifier Module with low noise, high linearity, and variable gain

Typical applications:

- Teleports & Earth Stations
- Satellite Operations
- Government & Defence applications
- Telemetry, Tracking & Command
- High Resilience applications

The C-Band low noise amplifier module is designed to work in the Genus 1U chassis series, operating over 850-4200 MHz. The module has low noise, high linearity, and +38 to 0 dB variable gain. The chassis has the capacity for up to 16 amplifier modules, or can house a mixture of other hot-swap module types.

Amplifier Module



Amplifier Module

Compact form factor allowing multiple modules to be housed in the Genus chassis. Each module occupies 1 slot in the chassis.



Hot Swap & replaceable RF Amplifier module



Variable Gain For signal optimisation.



C-Band 850-4200 MHz operating frequency range



Low Noise For prime signal quality



High Linearity Ensures overall RF gain signal performance is optimised

Chassis Options



Local control & monitoring via HMI high resolution touchscreen



Flexible Module Configurations choose from a mixture of amplifier modules with different operating frequencies.



Resilience from dual redundant hot-swap power supplies & field replaceable CPU & HMI



Remote control & monitoring via RJ45 Ethernet port with SNMP & web browser interface



Compact indoor & outdoor chassis options, which can be part populated



Field replaceable Internal 10MHz reference source and external reference inject port with auto detection (optional)



Secure protocols with SNMPv3 and HTTPS



Indoor Chassis



Outdoor Unit





| Smart Amplifier Module - RF Parameters | | | |
|--|------------------|--|---|
| Model Numbers | | ALT-G1S-C5-114-xxxx | |
| Frequency Range | | 850-4200 MHz | |
| RF Ports | | 50 ohm SMA | |
| Gain (dB) | Max. | 38±2 | |
| | Min. | 0±2 | |
| Gain Flatness (dB) | Full band | ±1.75 | |
| | 850 to 2450 MHz | ±1.25 | |
| | 3400 to 4200 MHz | ±1.25 | |
| | Any 36 MHz | ±0.25 | |
| Gain Steps (dB) | | 0.25±0.15 | |
| Input Return Loss (dB) | | 18 typ., 12 min | |
| Output Return Loss (dB) | | 18 typ., 12 min | |
| Isolation (dB) | Typ. | 60 | With amplifiers set at the same gain level. Worst case isolation is between adjacent amps, isolation degrades dB-to-dB for different gain levels. |
| | Min. | 50 | |
| Reverse Gain (dB) | | < -60 typ. | |
| Noise Figure (dB) | Typ. | 6.0 At max gain setting | |
| | Min. | 9.0 At max gain setting | |
| 1dB GCP (dBm) | Typ. | 16 At max gain setting | |
| | Min. | 13 At max gain setting | |
| OIP3 (dBm) | Typ. | 26 At max gain setting | |
| | Min. | 23 At max gain setting | |
| OIP2 (dBm) | Typ. | 38 | |
| | Min. | 35 | |
| In band, signal independent spuri | | <-85 dBm max. Very low level spuria from CPU clock, switch mode PSU and other control electronics inside the chassis | |
| Operating Temperature/Location | | 0 to 50°C | |
| Humidity | | 20 to 90% non-condensing RH | |
| MTBF | | >150,000 hrs. MTBF of each amp module. These are hot-swap | |
| Maximum Input Level | | +20 dBm. For no damage. None operational. | |
| Module Weight | | 0.35 kg | |
| Spec Version | | 0.1 | |

Note 1: The specification is subject to regular reviews and will be updated from time to time as part of our continuing product development and improved spec accuracy.
Note 2: Operation beyond the quoted limits stated above may cause instantaneous and permanent damage.

